

VRFA0026-QFN

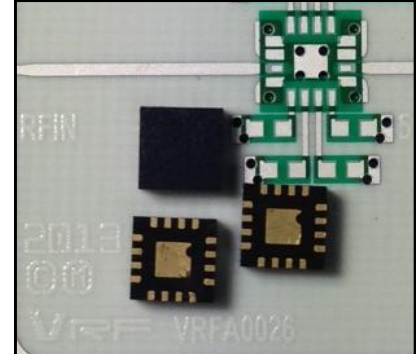


X-Band QFN Packaged GaAs MMIC LNA

Preliminary Datasheet v3

Features

- Frequency Range: 7 to 11 GHz
- Single supply 3V, 80mA self bias
- 1.2dB Noise Figure @ 9GHz typical
- 23dB small signal gain
- Rugged power handling capability
- 50Ω matched RF ports
- 3x3QFN package RoHS & REACH compliant



Description

The VRFA0026-QFN is an X-band low noise amplifier MMIC in a 3x3 QFN package which operates over the frequency range of 7GHz to 11GHz. The circuit demonstrates a nominal 1.2dB noise figure at 9GHz with small signal gain of 23dB across the frequency band. The VRFA0026-QFN draws 80mA from a +3VDC supply. The RF ports are DC blocked and matched to 50Ω. Typical applications for the VRFA0026-QFN include point to point radios, VSAT, radar and test & instrumentation.

Electrical Specifications

$T=+25^{\circ}\text{C}$ baseplate, $V_{DD}=+3\text{V}$, $I_d=80\text{mA}$

Parameter	Specification			Unit
	Max.	Typ. @9GHz	Min.	
Frequency Bandwidth	7		11	GHz
Small Signal Gain		23		dB
Noise Figure		1.2		dBm
I/P Return Loss		-8		dB
O/P return Loss		-9		
P1dB Ouput Power		15.5		dBm

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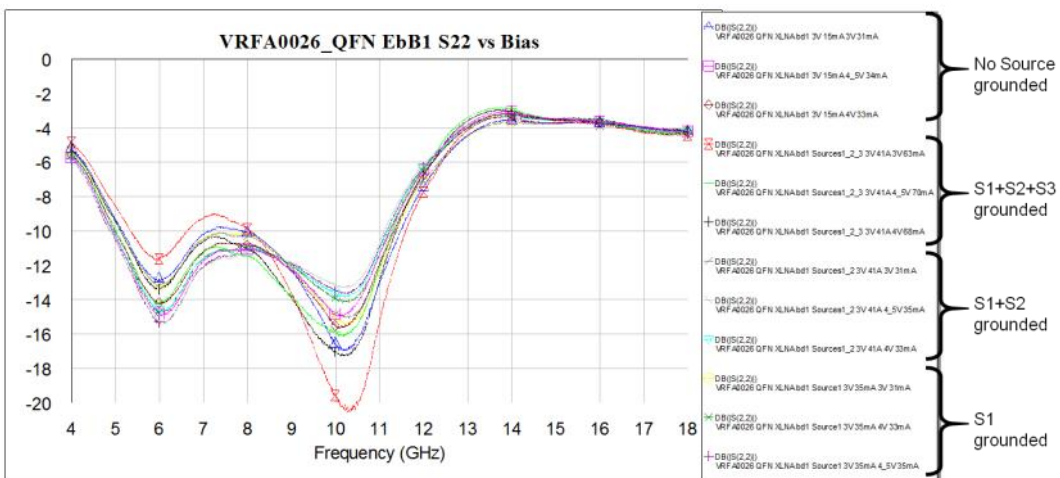
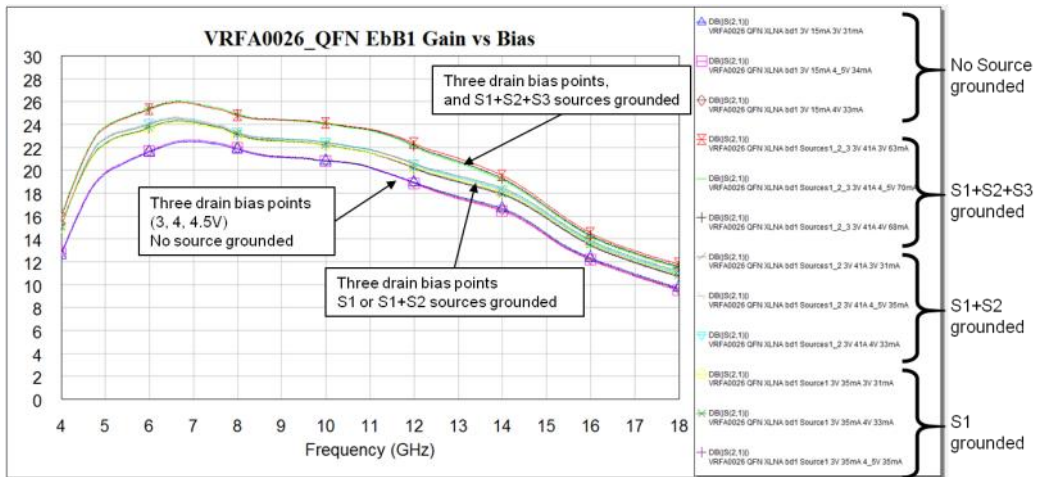
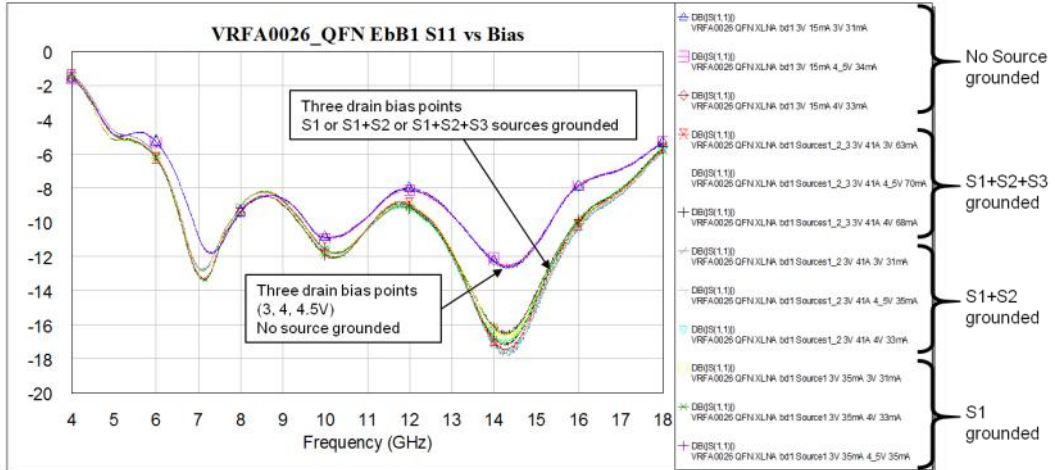


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Measured Performance

$T=+25^{\circ}\text{C}$ baseplate, $V_{DD} = +3\text{V}$



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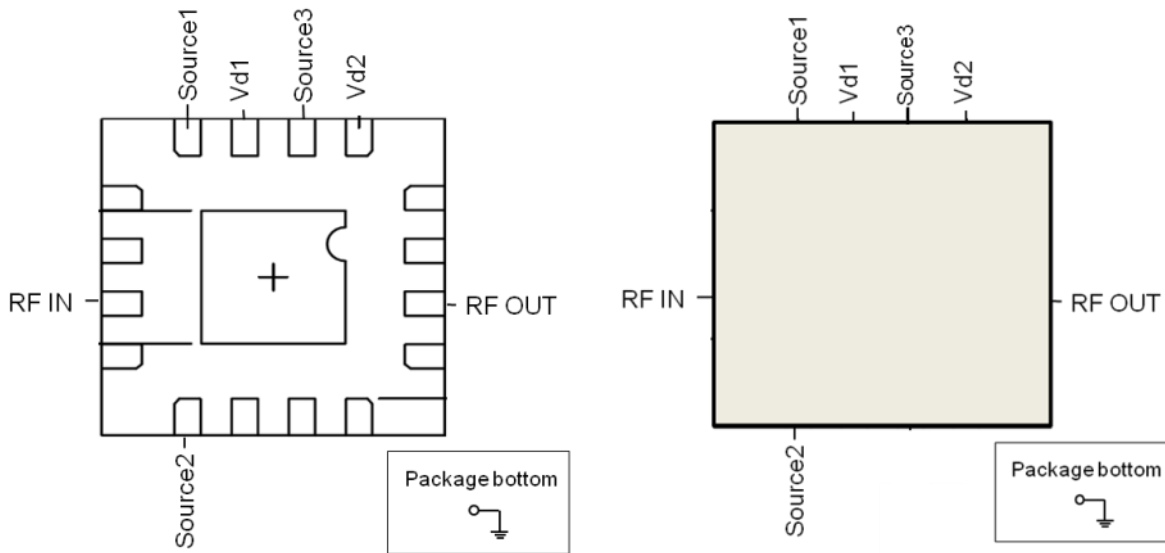
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Recommended Absolute Maximum Ratings ^[1]

Parameter	Symbol	Value	Notes
Drain Bias Voltage	V_d	+4V	
Gate Bias Voltage	V_g	-5V	
Gate Current	I_g	50mA	
RF input power (pulsed)	RF_{in}	+28dBm	Tested under 20% 40us Recommend maximum dependent on bias point
Junction Temperature	T_j	175°C	For maximum median device lifetime, T_j should be minimised
Storage temperature	$T_{storage}$	-55 to 150°C	

^[1] Operation outside these conditions may cause permanent damage to the device. Combination of maximum rating conditions may reduce the values. Device performance at these ratings is not implied.

Assembly & Bonding Diagram



VRFA0026-QFN Top View

VRFA0026-QFN Top View

PAD	CONNECTION
Vd1, Vd2	Device is self-biased, both connections are required
Source 1/2/3	Optional Connections to GND for optimize gain/NF/ compression
Package bottom	GND

Package Size	3mm x 3mm
Package Thickness	
Number of leads	16

GaAs devices are ESD sensitive and precautions should be observed during storage, handling, assembly and testing.

